

500mA,Ultra-low noise, Small Package Ultra-Fast CMOS LDO Regulator

General Description

The LP3980S is designed for portable RF and wireless applications demanding performance and space requirements. The LP3980S performance is optimized for battery-powered systems to deliver ultra low noise and low quiescent current. Regulator ground current increases only slightly in dropout, further prolonging the battery life. The LP3980S also works with low-ESR ceramic capacitors, reducing the amount of board space necessary for power applications, critical in hand-held wireless devices. The LP3980S consumes less than 0.03µA in shutdown mode and has fast turn-on time less than 50µs. The other features include ultra low dropout voltage, high output accuracy, current limiting protection, and high ripple rejection ratio.

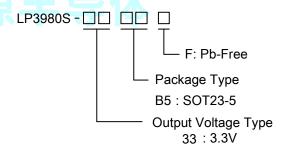
Applications

- ♦ Portable Media Players/MP3 players
- ♦ Cellular and Smart mobile phone
- ♦ LCD
- ♦ DSC Sensor
- ♦ Wireless Card

Features

- ◆ 1.6V- 5.5V Input Voltage Range
- ◆ Low Dropout : 240mV @ 300mA
- ◆ 500mA Output Current
- High PSRR: -76dB at 1KHz
- < 1uA Standby Current When Shutdown</p>
- Ultra-Fast Response in Line/Load transient
- Current Limiting
- ◆ Thermal Shutdown Protection
- Available in SOT23-5 Package

Order Information



Marking Information

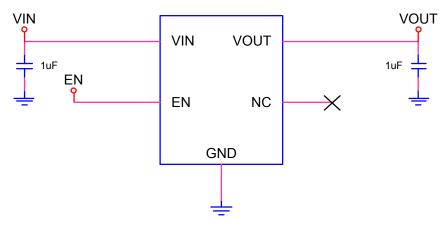
Device	Marking	Shipping		
LP3980S-33B5F	LP3980	3K/REEL		
LP39005-33B5F	33YWX			
Marking indication:				
Y:Year code .W: W is week code. X: X is series number.				

LP3980S-02

Sep.-2021



Typical Application Circuit



Functional Pin Description

Package Type	Pin Configurations		
SOT23-5	VIN 1 5 VOUT GND 2 LPSemi SOT23-5 (Top View)		

Pin Description

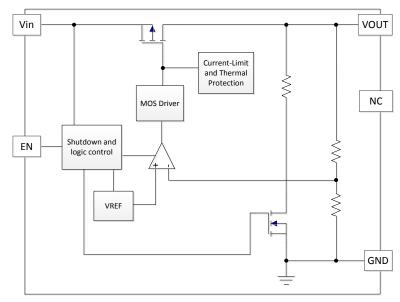
Pin No.	Name	Description
1	VIN	Power Input voltage.
2	GND	Ground.
3	EN	Enable pin.
4	NC	No connect.
5	VOUT	Output voltage.

LP3980S-02

Sep.-2021



Function Block Diagram



Absolute Maximum Ratings Note 1

\diamond	Input to GND	0.3V to 6V
	EN to GND	0.3V to 6V
	Output Voltage to GND	0.3V to (VIN+0.3V)
	Maximum Junction Temperature	150°C
	Operating Ambient Temperature Range (T _A)	40°C to 85°C
\diamond	Maximum Soldering Temperature (At leads, 10 sec)	260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

\Rightarrow	Maximum Power Dissipation (SO123-5, P_D , T_A =25°C	5)	400mVV

♦ Thermal Resistance (SOT23-5, θ_{JA}) ------ 250°C/W

ESD Susceptibility

\diamond	HBM(Human Body Mode)		2KV	
------------	----------------------	--	-----	--

♦ MM(Machine Mode) ------ 200V

LP3980S-02

Sep.-2021



Electrical Characteristics

 $V_{\text{IN}} = V_{\text{OUT}} + 1V$, $C_{\text{IN}} = C_{\text{OUT}} = 1 \mu F$, $T_{\text{A}} = 25 ^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parame	Parameter Test Conditions		Min	Тур	Max	Units
VIN	Input Voltage			1.6		5.5	
V _{OUT}	Output Voltage		I _{OUT} = 1mA		3.3		V
ΔV_{OUT}	Output Voltage	Accuracy	I _{OUT} = 1mA	-1		+1	%
I_{LIM}	Current I	_imit	$R_{LOAD} = 1\Omega$		650		mA
IQ	Quiescent Current		V _{EN} ≥ 1.2V, I _{OUT} = 0mA		20		μA
	Dropout Voltage Line Regulation		I _{OUT} = 200mA		160	200	mV
V_{DROP}			I _{OUT} = 300mA		240	300	mV
			I _{OUT} = 500mA		400	500	mV
ΔV_{LINE}			$V_{IN} = (V_{OUT} + 1V) \text{ to } 5.5V, I_{OUT} = 1\text{mA}$			0.1	%
ΔV_{LOAD}	Load Regulation		1mA < I _{OUT} < 300mA			0.6	%
I _{STBY}	Standby Current PSCII EN Input Bias Current		V _{EN} = GND, Shutdown	mi	0.03	1	μA
I _{IBSD}			V _{EN} = GND or V _{IN}		0.1	1	uA
VIL	EN Threshold	Logic-Low Voltage	V _{IN} = 3V to 5.5V, Shutdown	4		0.4	V
V_{IH}	EN THESHOLD	Logic-High Voltage	V _{IN} = 3V to 5.5V, Start-Up	1.4			V
-	Output Noise Voltage		$f = 10Hz$ to $100kHz$, $I_{OUT} = 0mA$ $V_{OUT} = 2.8V$		100		uVRMS
PSRR	Power Supply	f=217Hz	0 45 50 6		-80		dB
	Rejection Rate f=1KHz		$C_{OUT} = 1\mu F, I_{OUT} = 50mA$		-76		dB
T _{SD}	Thermal Sh Tempera				150		°C

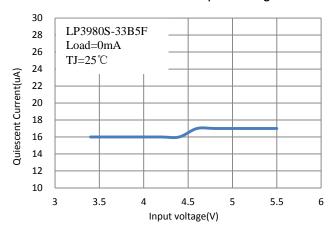
LP3980S-02

Sep.-2021

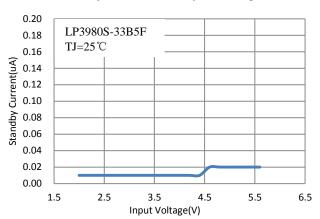


Typical Operating Characteristics

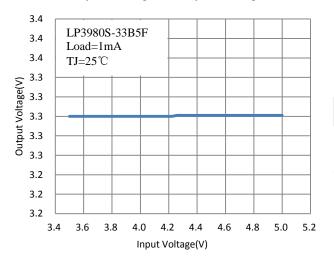
Quiescent Current VS. Input Voltage



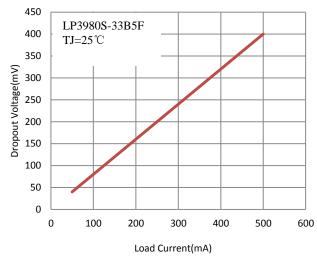
Standby Current VS.Input Voltage



Output Voltage VS.Input Voltage



Dropout Voltage VS. Load Current





Applications Information

Like any low-dropout regulator, the external capacitors used with the LP3980S must be carefully selected for regulator stability and performance. Using a capacitor whose value is > 1µF on the LP3980S input and the amount of capacitance can be increased without limit. The input capacitor must be located a distance of not more than 0.5 inch from the input pin of the IC and returned to a clean analog ground. Any good quality ceramic or tantalum can be used for this capacitor. The capacitor with larger value and lower ESR (equivalent series resistance) provides better PSRR and line-transient response. The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all LDOs application. The LP3980S is designed specifically to work with low ESR ceramic output capacitor space-saving and performance in consideration. Using a ceramic capacitor whose value is at least $1\mu F$ with ESR is > $25m\Omega$ on the LP3980S output ensures stability. The LP3980S still works well with output capacitor of other types due to the wide stable ESR range. Output capacitor of larger capacitance can reduce noise and improve load transient response, stability, and PSRR. The output capacitor should be located not more than 0.5 inch from the VOUT pin of the LP3980S and returned to a clean analog ground.

Enable Function

The LP3980S features an LDO regulator enable/disable function. To assure the LDO regulator will switch on, the EN turn on control level must be greater than 1.4 volts. The LDO regulator will go into the shutdown mode when the voltage on the EN pin falls below 0.4 volts. For to protecting the system, the LP3980S have a quick-discharge function. If the enable function is not needed in a specific application, it may be tied to VIN to keep the LDO regulator in a continuously on state.

Thermal Considerations

Thermal protection limits power dissipation in LP3980S. When the operation junction temperature exceeds 150°C, the OTP circuit starts the thermal shutdown function turn the pass element off. The pass element turns on again after the junction temperature cools by 20°C. For continue operation, do not exceed absolute maximum operation junction temperature 125°C.

The power dissipation definition in device is :

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{O}$$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junctions to ambient.

The maximum power dissipation can be calculated by following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

LP3980S-02

Sep.-2021



Where $T_{J(MAX)}$ is the maximum operation junction temperature 125°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance. For recommended operating conditions specification of LP3980S, where $T_{J(MAX)}$ is the maximum junction temperature of the die (125°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance (θ_{JA} is layout dependent) for SOT23-5 package is 250°C/W.

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / 250 = 400 \text{mW (SOT23-5)}$

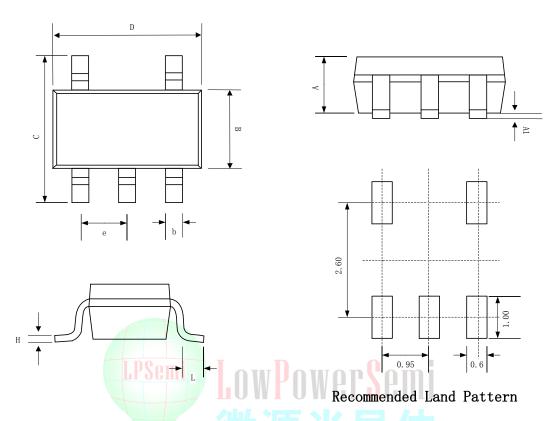
The maximum power dissipation depends on operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance θ_{JA} .





Packaging Information

SOT23-5



SYMBOL	Dimensions In Millimeters				
STIVIBOL	MIN	NOM	MAX		
Α	0.889	1.100	1.295		
A1	0.000	0.050	0.152		
В	1.397	1.600	1.803		
b	0.28	0.35	0.559		
С	2.591	2.800	3.000		
D	2.692	2.920	3.120		
е	0.95BSC				
Н	0.080	0.152	0.254		
L	0.300	0.450	0.610		